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1 INTRODUCTION

This Master's thesis is focused on Piezoelectric Energy Harvesting in general. Apart from the explanation of the actual energy scavenging process, it also covers a design of a proper data acquisition system used for evaluation and development of piezoelectric-based generators.

1.1 Motivation

Nowadays, electrical energy itself is taken for granted by most of the people. It may be a result of the fact that most of household appliances and daily use items require that energy to operate. Moreover, almost any of our tasks require a proper illumination, Internet access or simply the outlet to live any tool we might need at the moment. To conclude, it is almost impossible to imagine our life without an access to the power grid.

On the other hand, it is important to keep in mind that most of electricity we utilize comes from non-renewable fuels such as coal, liquid gas or crude oil. At some point, humankind is to face a problem of insufficient deposits of these materials, therefore it tremendously important to look for alternatives. Of course, people have already taken advantage of water, wind or solar radiation, what is proven by the existence of many green power plants around the world. Unfortunately, one of the major problems faced by all of these plans is the intermittent access to the energy source. Moreover, there are many places that does not allow to use any of these well explored solutions, forcing engineers to look for new ones. This could be a reason why vibrational energy is getting more awareness over last years.

Energy harvesting from vibration gives many new possibilities, especially in IoT (Internet of Things) applications, as well as in industrial environment. The second application seems particularly tempting, as in many industrial applications, there is a lot of vibration involved, what gives a wide scope for custom sensor development. Piezoelectric harvesters are relatively compact, therefore it is possible to install them in inaccessible places. Moreover, they are robust, providing that a proper enclosure is used for mechanical protection.

All of mentioned factors gained author's interest, and in the event prompted to work on this subject within the confines of this thesis.

1.2 Objective of a Master's thesis

The main goal stated by the author is to examine a potential of vibration-based energy scavenging. In order to do so, number of different aspects need a thorough investigation. Undeniably, much of the focus would be put on the energy harvester itself. Nevertheless, a proper measurement and data acquisition system is also an important aspect throughout the entire work, since it will allow confirm or deny thesis statements posed during the research. In addition, the design process of the mentioned device would allow a more in-depth analysis of the piezoelectric generator itself, since the understanding of its operation is the only way to come up with a suitable measurement system.

Returning to the piezoelectric generator, the first thing to look at is the theory behind the piezoelectric effect. Then, there would be a description of the piezoelectric cantilever and its properties. Subsequently, the complete mechanical and electrical model would be studied.

Once the required theory is introduced, it is possible to focus exactly on the topic.

2 CONCEPT OF ENERGY HARVESTING

Energy Harvesting is a process of using ambient energy by converting it into a usable form, i.e. electricity or heat. It is important to point out that energy harvesting has been around for quite a long time, since solar panels, wind turbines and water turbines are in constant use for a few decades, providing people with environmentally clean energy [1].

There are some important issues related to any energy source that could be potentially used for harvesting. First of all, it is crucial to evaluate intensity and availability of that source. Subsequently, one should find out a cost-effectiveness of the solution as well as the influence of the harvesting process on the primary energy source [1].

Vibration-based Energy Harvesting incorporates a number of different fields of study, i.e. material science, mechanics or electrical engineering, just to name a few. Last sentence implies that the analysis of a piezoelectric generator itself is not a straightforward process. The electromechanical response of this device relies thoroughly on the source of ambient energy [2].

The concept of piezoelectric energy harvesting is strongly related to the improvement of electronics manufacturing technologies. Due to fact that most of devices are becoming more energy efficient, it allows to seek for potentially useful energy in solutions that have been neglected before. This perfectly applies to vibrational energy [3].

2.1 Piezoelectric material utilized in harvesters

Currently, the most popular material utilized in harvesters is so called PZT (lead zirconate titanate). It was developed at the Tokyo Institute of Technology in the 1950s [2]. Nowadays, it can be found in a few different flavours, what would be described more precisely later. This material is a polymer composite, which is very brittle and prone to crack when overstressed[4].

As described in the previous paragraph, PZT has a number of different types that vary with electrical and electromechanical properties. The simplest division includes hard and soft types - PZH-5H and PZH-5A, respectively. Soft piezoceramics are more susceptible to changes caused by the stress. This is one of the aspects why PZH-5H is the most common choice for piezoelectric equipment. On the other hand, one of the biggest manufacturers of harvesters [5] is mentioning that PZH-5A is more temperature stable. Nevertheless, PZH-5H remains the best choice in terms of performance versus price.

Properties of piezoelectric materials strongly depend on the direction of the stress and orientation of the polarization [1]. It is characterized by the constants listed in the Table

2.2 Efficiency and power density

Piezoelectric generator is truly a non-linear device. It produces maximum output power at its resonance frequency, which depends on a number of factors.

Power density of the harvesters is expressed as the output power divided by the device volume for the given input [2]. In case of vibrational energy, the input is the acceleration level and the frequency. An output of the piezoelectric generator provides voltage levels suitable for many electronics systems, therefore it is often unnecessary to add additional power electronics, what has an influence on efficiency.

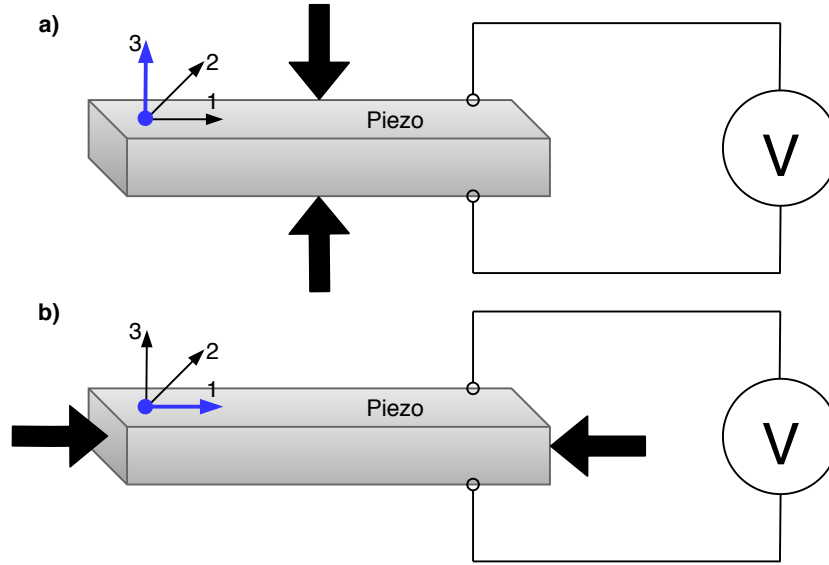


Figure 2.1: Operation modes of the piezoelectric element

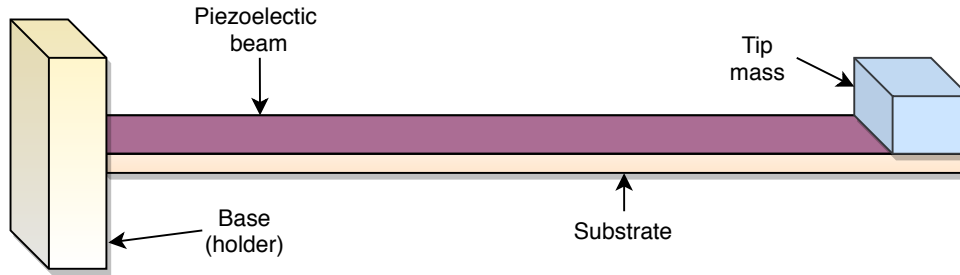


Table 2.1: Common data for some of Energy Harvesting Sources [1]

Type	Conditions	Power Density	Area or Volume	Energy/Day
Vibration	$1m/s^2$	$100\mu W/cm^3$	$1cm^2$	$8.64J$ (continuous vibration)
Solar	Outdoors	$7500\mu W/cm^2$	$1cm^2$	$324J$ (sunny half a day)
Solar	Indoors	$100\mu W/cm^2$	$1cm^2$	$4.32J$ (sunny half a day)
Thermal	$\Delta T = 5^\circ C$	$60\mu W/cm^2$	$1cm^2$	$2.59J$ (heat available for half a day)

2.3 Clamping

Effective clamping is really important for piezoelectric beams. In order to achieve best performance, it is crucial to provide proper holder that gives reliable operation regardless of vibration level - see Figure 2.2.

For the sake of this project, the holder provided by the manufacturer would be used for evaluation purposes. The clamp bar is going to hold the beam in place with help of bolts and washers.

According to the manufacturer's datasheet [5], the second position of the clamp is a default configuration for all products. The third position of the clamp comes in handy when one need to increase the resonant frequency of the piezo wafer. On the other hand, the first position reduces the resonant frequency. It is noted that this hardware configuration is not recommended for energy harvesting applications due to stiffness issues.

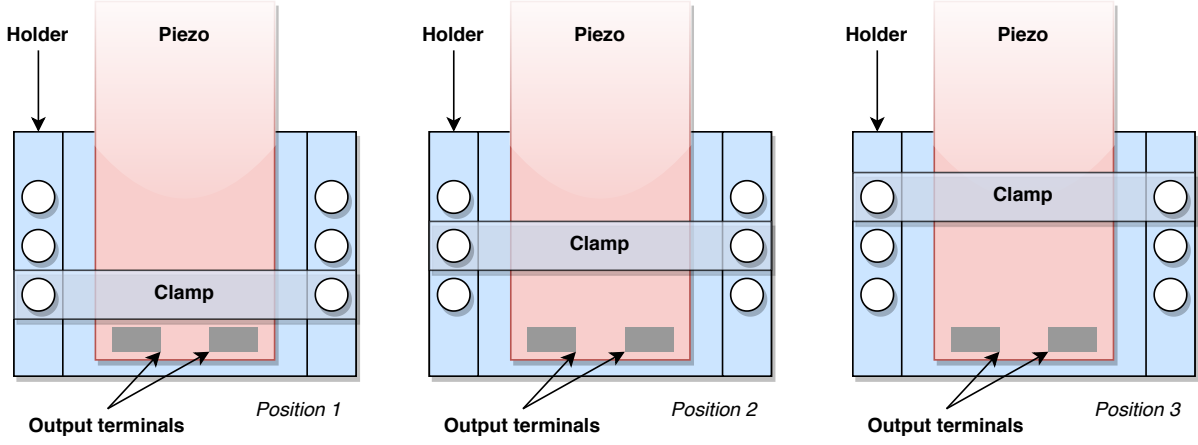


Figure 2.2: Clamping problem explanation

2.4 Tip mass

Piezoelectric energy harvesters are frequency-dependent devices. In order to achieve their maximum efficiency, it is necessary to operate close to its resonant frequency. Piezoelectric beams may need some tuning procedures in order to match the frequency of the vibrating source, thus allowing to ensure most energy efficient harvesting.

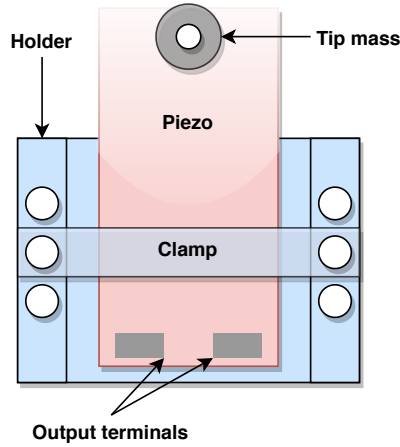


Figure 2.3: Tip mass illustration

As mentioned in the previous subsection, frequency tuning may be performed by changing the clamp position. Unfortunately, this option does not allow for precise trimming, therefore additional techniques are often required. One of the most popular ones incorporated the tip mass attached at the end of the piezoelectric wafer. Providing that the operating frequency is fixed and known, it is possible to determine the exact tip mass required to tune the beam:

$$f_{natural} = \frac{\sqrt{\frac{k}{m+m_t}}}{2 \cdot \pi} \quad (2.1)$$

$$m_t = \frac{k}{(2 \cdot \pi \cdot f_{natural})^2} - m \quad (2.2)$$

3 MEASUREMENT SETUP DESIGN

A proper measurement process is a crucial part of this project. Having said that, a custom data acquisition board is to be designed.

First of all, it is vital to highlight most important features required to achieve desired performance. There are four major aspects that have to be taken into account, namely, the ADC resolution as well as the input voltage range, the bandwidth and high input impedance of the analog front-end. Apart from that, one should take care of easy interfacing to personal computer, thus compact size and USB interface would be considered as huge assets.

The previous paragraph introduced briefly main functionalities of the target device. It is quite easy to notice that there would be a lot of trade-offs to consider through the design process. Compact size and the complex analog circuitry usually do not mix, especially when planning to get a device of USB mass storage size. These facts are forcing the designer to look for a microcontroller that provides decent ADCs, also in terms of the sampling rate. Since the project is dealing with piezoelectric generators, there is always a risk of relatively high voltages at the input terminals, especially when harvesters are not connected to any load. To face this problem, the data acquisition board would be equipped with two different means of protection. The first one takes care of the input stage of the device. The second one is a classic galvanic isolation between the microcontroller (as well as the analog front end) and the personal computer. This way, there is no risk of damaging host devices utilizing the data acquisition system. The summary of the above-mentioned description is presented in the Figure 3.1.

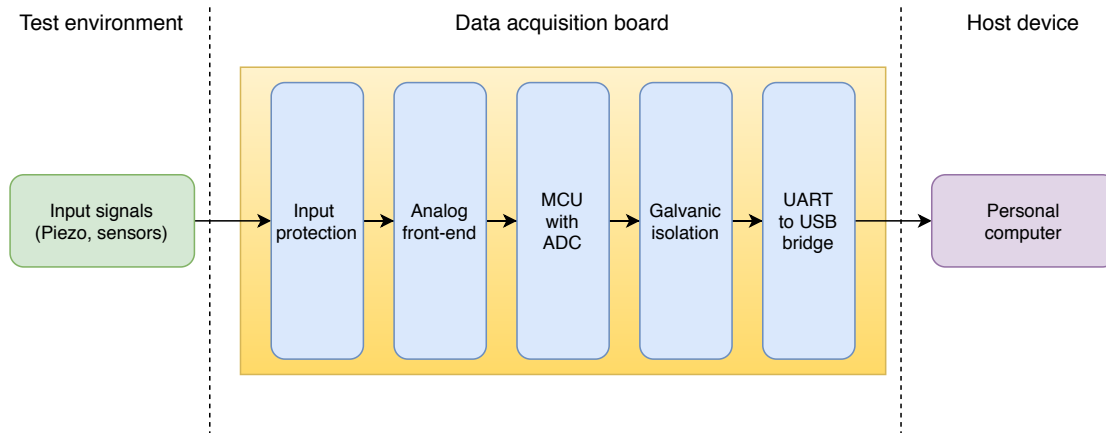


Figure 3.1: Measurement setup overview

3.1 Design requirements

The first step of the design process is to determine desired input ratings as well as data acquisition capabilities. The piezoelectric device used in this project would be the major signal source during all experiments. Its datasheet [5] does not state any fixed maximum ratings. Instead, it provides exemplary results obtained by varying acceleration amplitude, frequency, tip mass and load resistance - see Table 3.1.

As mentioned in the previous paragraph, there is no constrained area in terms of vibration frequency and level stated by the manufacturer. Based on the data presented in the Table 3.1, the designer is relatively free to determine the operating frequency range as well as input signal range recorded at the harvester's output. When considering bandwidth and sampling rate, it is important to take into account the Nyquist criterion. It states that the sampling rate has to

3 Measurement setup design

Table 3.1: Exemplary piezoelectric harvester response. Data from PPA-1001 datasheet [5]

Acceler. ampl. (<i>g</i>)	Freq. (<i>Hz</i>)	Tip mass (<i>gram</i>)	RMS power (<i>mW</i>)	RMS voltage (<i>V</i>)	RMS current (<i>mA</i>)	Load (<i>kΩ</i>)
0.25	132	0.0	0.1	1.1	0.1	17.9
0.50	131	0.0	0.2	1.9	0.1	18.3
1.00	131	0.0	0.7	3.4	0.2	15.7
2.00	129	0.0	2.2	5.4	0.4	13.0
0.25	60	1.9	0.1	2.9	0.0	61.0
0.50	60	1.8	0.5	3.3	0.2	20.8
1.00	60	1.7	1.8	7.1	0.3	28.6
0.25	22	22.8	1.4	9.0	0.1	60.4
0.50	22	22.8	4.4	17.3	0.3	67.6

be twice the highest frequency in the signal [6]. Assuming maximum vibration frequency of 500Hz, more than 1000 samples per second need to be captured.

Of course, this sampling rate only allows to reproduce an incoming signal (sinusoidal wave) as a corrupted triangle, since there is not enough data points to accurately reflect the sine shape. To solve this problem, the sampling rate should be increased by factor of 5 or so, what ultimately yields at least 5000 samples per second (sps). To illustrate the problem, Figure 3.2 is introduced. It can be easily seen that sampling rate as high as twice the input signal frequency is definitely not enough. Having said that, the minimum expected sampling rate is to be at least 5000 sps.

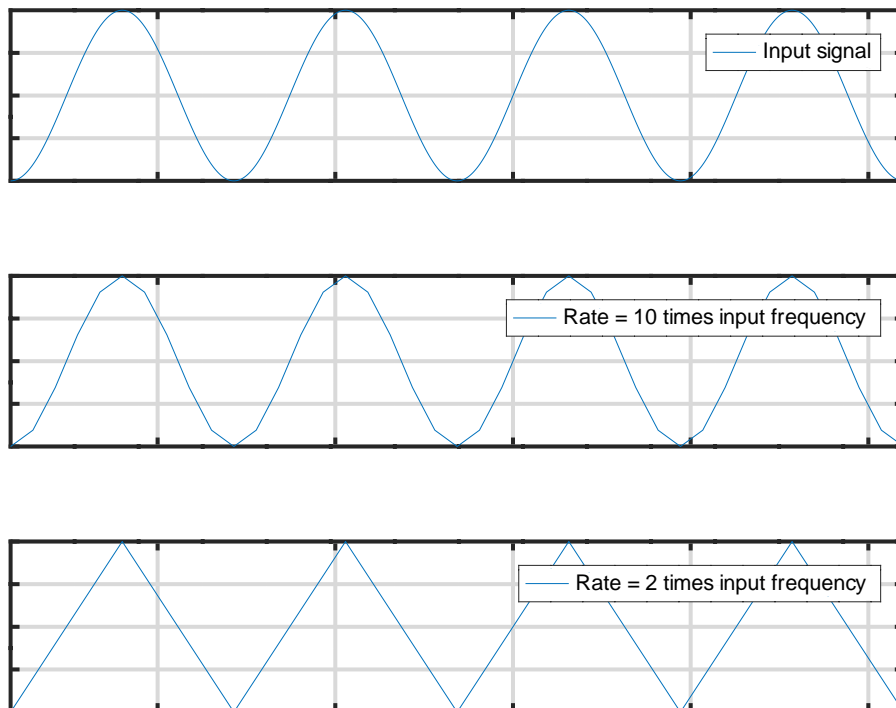


Figure 3.2: Captured waveform versus sampling rate

It is likely that the microcontroller used in the data logger would use some kind of a serial

communication protocol. Assuming that more than one signal is recorded at the time and the baud rate is fixed at the same level, the maximum input signal frequency would be divided by the number of active channels. For example, for 2 channel measurement, the maximum input signal frequency is 250Hz and so on.

One of the previous paragraphs mentioned the piezoelectric harvester as the main input signal source. Knowing that the device produces a sinusoidal output, the analog front-end has to be able to capture AC signals, preferably of a relatively high amplitude. This requirements force the designer to develop symmetrical power supply for the input section as well as the circuitry allowing to add offset to the signal before it reaches the ADC input. A reason is that the ADC of the microcontroller is likely to accept only unipolar signals within tightly specified range. Remaining channels would be able to interface DC signals only, what makes them suitable for external sensors such as the accelerometer.

When considering the maximum input signal level, one has to note that it should not exceed supply voltage of operational amplifier used in the input section. In case of the designed device, the power supply would be industrial $\pm 15V_{DC}$, as it helps to maintain compatibility with wide range of available operational amplifiers. Based on the last sentence, the maximum input voltage is specified to $\pm 15V$ for the AC input and $+15V$ for DC inputs. In order to assure proper operating conditions for the analog-front end, an additional input protection is to be provided.

There are two last aspect that need some care. The first one is the resolution of the ADC that would be used to capture the incoming signal. The second one is the input impedance of input channels.

As to the first point, it is useful to have a look at technical details of commonly available oscilloscopes, since they can be treated as a nice reference. Most of them utilize 8 or 10-bit ADCs, mostly because of bandwidth requirements as well as the sampling time. In case of this design, the bandwidth is significantly reduced, what allows to look for a bit more resolution, of course still bearing in mind that all the processes are handled by one modest microcontroller. Putting it all together, an 14-bit ADC is going to be a desired data converter.

The last point relates to the impedance of analog inputs. Piezoelectric harvesters are high output impedance devices [1], therefore it is desirable to maintain as high input impedance of the analog front-end as possible, in order not to disturb the incoming signal. There are two potential problems that may occur when designing the input stage. As it can be guessed, the input signal has to be divided before it gets to the analog-to-digital converter. The easiest way to go is to put a voltage divider directly at the output of the harvester. Unfortunately, this circuit would have a significant influence on the impedance seen from piezo generator's output terminals, thus posing a risk of changing its operating conditions. To deal with this problem, the incoming signal is to be buffered before any further processing. This is where low input bias current operational amplifiers would come in handy. The second risk is related to the protection circuitry attached to input terminals. Once the input signal gets to high, it would be clamped in order to protect the data acquisition board. Unhappily, it would also disturb the measured object due to rapid change of the impedance seen at mentioned harvester's output terminals. The only way to deal with this issue is to provide relatively high supply voltage for buffering amplifiers and adjust the load as to meet the input voltage requirements.

As a summary of design considerations included in this subsection, Table 3.2 has been created.

Table 3.2: Summary of requirements for the data acquisition board

Requirement	Value
Max. input signal frequency (Sine)	500Hz
Min. sampling rate	5000sps
Min. ADC resolution	14-bit
Max. input voltage range (p-p)	15V
Input impedance	TBD

3.2 Accelerometer board

As it has been previously mentioned, it is necessary to constantly monitor vibration level during all the experiments. These measurements will be a reference for the results obtained using the piezoelectric harvester, as they easily allow to correlate generated power and current vibration level.

The piezoelectric beam used throughout the research is mounted in a 3D-printed holder provided by the device manufacturer. Apart from a proper fit, it allows to attach some external electronics by means using nice mounting holes. It is worth to take advantage of this feature, therefore designed electronics would be compatible with the handler.

3.2.1 Most important parameters of the accelerometer

As to the electrical and electromechanical properties of the accelerometer, there are a few aspects that should be highlighted. The first one is the measurement range. By checking the maximum acceleration of the beam, it is possible to estimate required range for the sought integrated circuit. Next, the frequency response and output signal type need to be determined. Frequency response describes the measurement resolution that could be understood as the smallest detectable acceleration [7]. By mentioning the type of the output signal, it was intended to distinguish between analog and digital output types. It is planned to synchronize the accelerometer output with the piezoelectric cantilever response, so the analog output is more suitable and easier to use.

Harvester's datasheet [5] does not mention the exact upper limit of allowed vibration level. According to the Table 3.1, the maximum acceleration amplitude mentioned by the manufacturer is $2g$. Without any additional information, it is reasonable to treat this value as the upper acceleration limit. The same applies to the frequency response, which is also not described precisely. Again, Table 3.1 states the maximum operation frequency at the level of 132Hz. In this case, the minimum acceptable bandwidth of the accelerometer would be roughly 200Hz. As it was mentioned in the previous paragraph, it is intended to use the analog output accelerometer. A summary of the above-mentioned choices is presented in the Table 3.3.

Table 3.3: Summary of requirements for the accelerometer

Requirement	Value
Max. acceleration value	$\pm 2g$
Max. operating frequency	300Hz
Output type	Analog

3.2.2 Selection of the integrated circuit

After a thorough market research, a proper device has been found - see Table 3.4. Apart from parameters listed in the table, the selected accelerometer has the following features: small SMD package, 3.3V supply operation, low power consumption and tunable bandwidth filters for every axis. Moreover, it exhibits non-linearity at a level of 0.3% [8].

Table 3.4: Parameters of the selected parameter - taken from the datasheet [8]

Parameter	Value
Model	ADXL335
Manufacturer	Analog devices
Output type	Analog
Max. acceleration value	$\pm 3g$
Bandwidth	up to 1600Hz

As it can be seen, the above-mentioned device fulfils the requirements presented in the previous subsection. At this point, it is necessary to think about additional circuitry allowing to take advantage of the selected integrated circuit. In order to do so, a small PCB is to be designed.

3.2.3 Accelerometer board design

The accelerometer board should be a battery powered device, as it is going to be used throughout tests in different types of environment, many times without an access to any power supply. Moreover, battery operation allows for a better performance in terms of noise generated on supply rails. Additionally, the board is ought to be equipped with a temperature sensor, in case some tests are to be performed in extreme temperatures and the exact temperature value is needed to know.

Figure 3.3 presents the diagram of designed board. It can be divided into two main parts, namely a power supply with a battery charger and a sensing part including the accelerometer and the temperature sensor.

As to the power supply part, for the convenience, the entire board is powered using a micro USB port, which is fused for safety purposes. Right after the input, there is a single cell battery charger (BRCL4054CME by Blue Rocket Electronics [9]). Charging current is set using just one resistor. Moreover, it incorporates such function as C/10 charge termination, a soft-start feature as well as an open-drain output used for signalling purposes.

Power storage is maintained by means of a 110mAh lithium-polymer battery (LIPO511422 by MAXPOWER). It is equipped with a complete protection circuitry, so it is unnecessary to include additional protection on the accelerometer board. The battery manufacturer claims the cycle life of 1000 cycles.

Right after the ON/OFF switch, there is a low dropout linear regulator supplying the rest of circuits (AP2112K-3.3TRG1 by Diodes Incorporated [10]). It is a 600mA output, low noise regulator with $\pm 1\%$ output voltage accuracy.

One of the sensors placed on this board is the accelerometer mentioned in the previous section. The second one is a low-power linear temperature sensor (MCP9700T-E/TT by Microchip [11]). Since the linear output is one of the requirements for all sensors used in this project, this kind of device was an easy choice. MCP9700 includes circuitry converting temperature to voltage and provides accuracy of $\pm 2^\circ\text{C}$, which is by all means acceptable for this application.

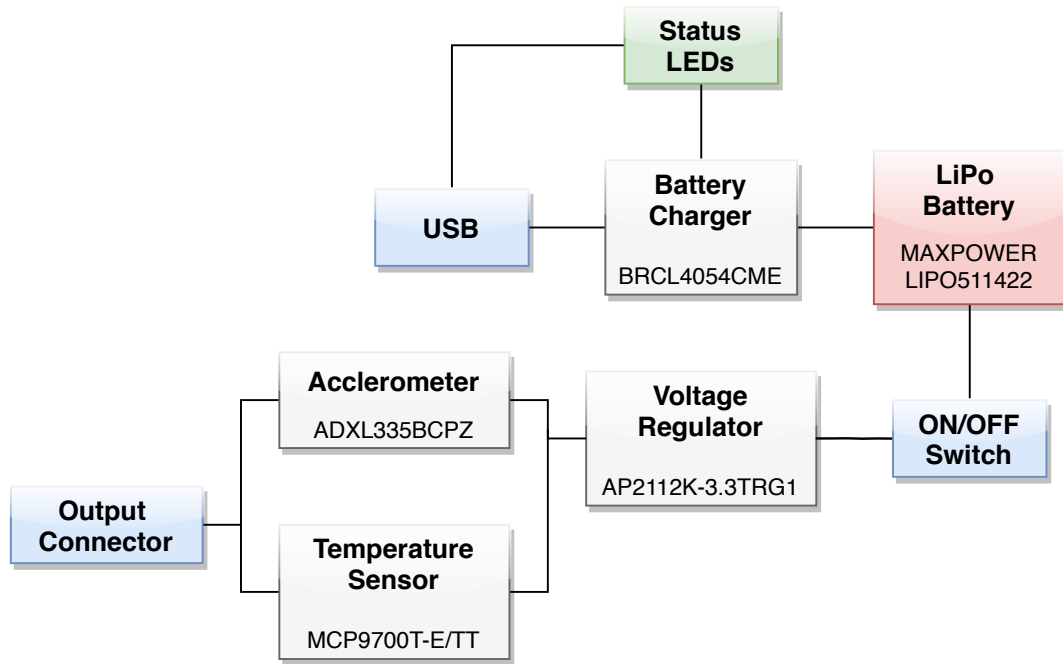


Figure 3.3: Accelerometer board diagram

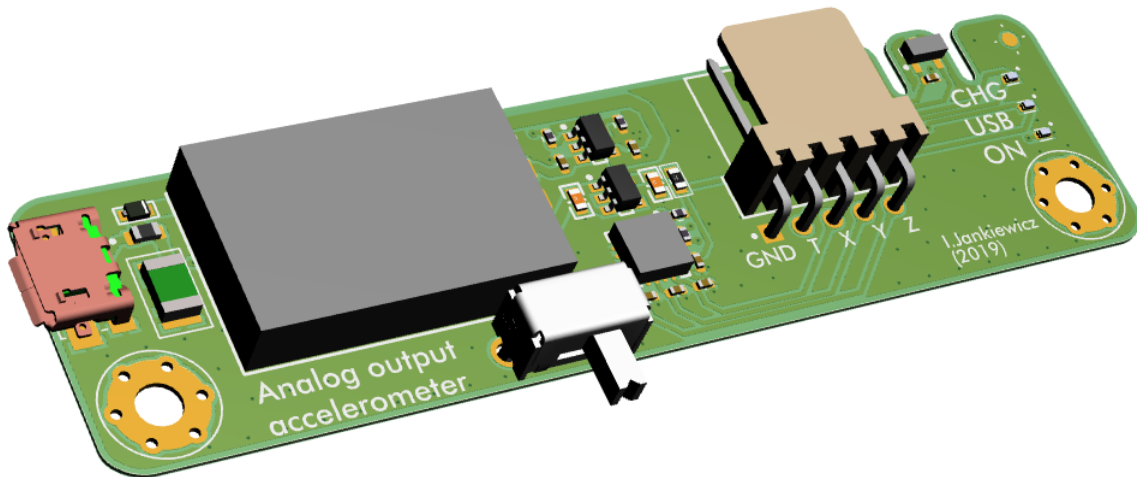


Figure 3.4: Accelerometer board top side view

Figures 3.4 and 3.5 present the final design. As it can be seen, a relatively compact and intuitive device has been developed. A standard connector with 2.54mm pitch is used to allow easy access to the board. There are two reinforced holes for mounting screws. The bottom side of the PCB includes large past allowing to solder cables connected to piezoelectric beam terminals in order to make the construction more robust.

This board is going to be an inherent part of most experiments performed throughout this thesis.

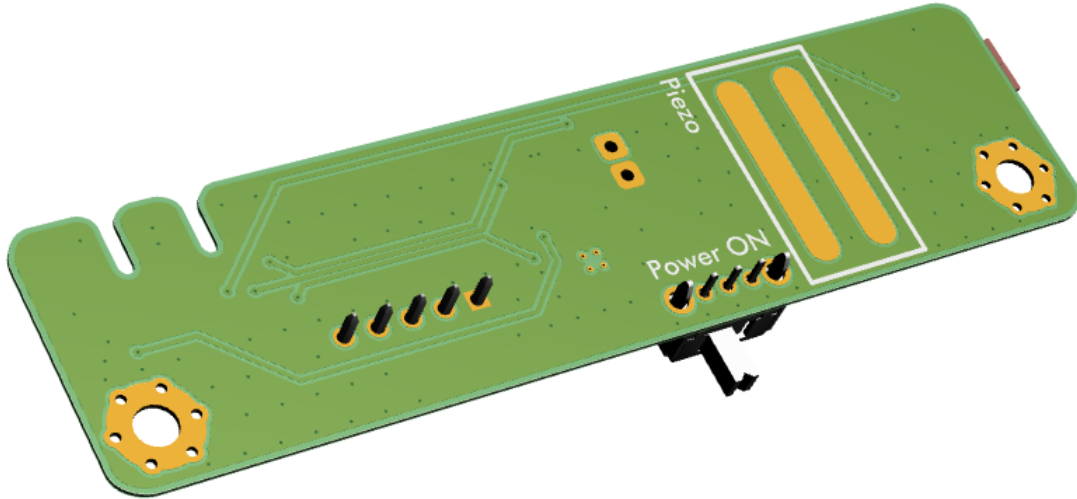


Figure 3.5: Accelerometer board bottom side view

3.3 Data acquisition board design

3.3.1 AC input section

The data acquisition board is going to be equipped with one AC-tolerant input channel. This feature will be helpful in cases when piezoelectric beam is loaded only with a resistive load, hence there is no rectification action present. In order not to damage the microprocessor and other circuitry that is powered from a single supply, some signal conditioning is required.

3.3.1.1 Input protection

An important aspect (often overlooked though) is proper input protection for analog circuitry. At this point it is important to highlight that signal conditioning would be based on a variety of different operational amplifiers. Having said that, one should consider problems related to these devices as well as the influence of protection circuit on measurement results.

One of most popular means of protection for op-amps are clamping diodes along with current limiting resistors. Nowadays, popular operational amplifiers incorporate ESD protection diodes into their input circuitry, which is surely very helpful in most cases, nevertheless it can be a source of potential problems. These diodes are clamped to supply rails in order to provide return path for currents generated by ESD-related events. These happen once the input voltage gets higher than supply rail voltage plus voltage drop (usually around 0.7V) or lower than negative rail voltage minus the diode voltage drop, respectively [12]. In normal conditions these diodes remain transparent.

It is important to remember that the clamping circuit is going to have an influence on measurement results if designed improperly. Now, it is time to recall a very important parameter related to inputs of the operational amplifier, namely the Input Bias Current I_{bias} , which is inherently related to any "real" (and non-ideal) Op Amp. It's value is going to have a direct influence on the clamping circuit design, what would be explained in a more detailed manner soon.

The Input Bias Current I_{bias} is a DC current required by the Op Amp's inputs to establish proper biasing of input stage transistors [13]. It ranges from a few picoamps to a few microamps.

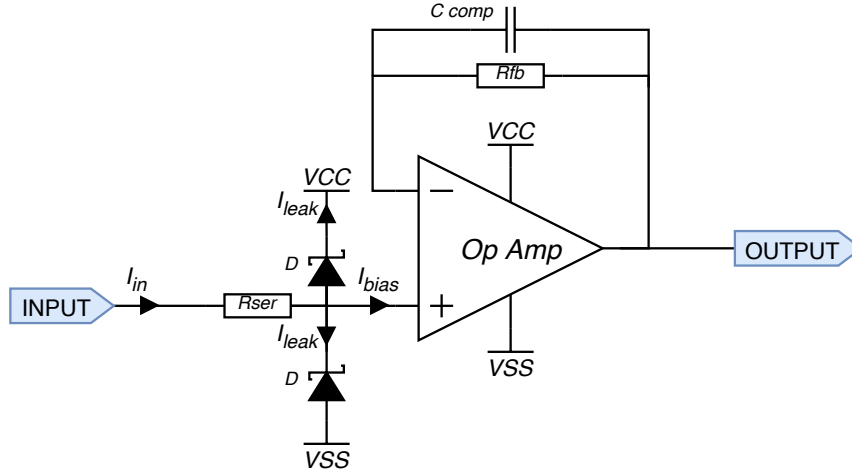


Figure 3.6: Clamping overvoltage protection scheme

This current is going to flow through the series protection resistor, generating a voltage drop proportional to mentioned current value multiplied by the series resistance. The explanation is presented in the Figure 3.6.

Another unwanted, but also unavoidable error source is the Reverse Leakage Current I_{leak} of clamping diodes, which depends on the value of reverse voltage applied to its terminals. All unwanted currents add up and flow through the series protection resistor R_{ser} generating the voltage drop. The total error voltage V_{error} is equal to the mentioned voltage drop multiplied by the gain of the operational amplifier A_u - see Equation 3.1.

$$V_{error} = (R_{ser} \cdot (I_{bias} + I_{leak1} + I_{leak2})) \cdot A_u \quad (3.1)$$

Of course, apart from the error generation, the clamping circuit plays a crucial role in operational amplifier's inputs protection, since it allow to deal with excessive voltage without any problems. The maximum continuous input voltage can be calculated if the value of series resistance, the Forward Continuous Current I_f , op-amp supply voltage V_{cc} and the diode forward voltage drop V_{fd} are known. Peak input voltages can even be even higher, as this parameter depends strongly on the current value flowing through the protection diode.

$$V_{in(MAX)} = V_{cc} + R_{ser} \cdot I_f + V_{fd} \quad (3.2)$$

To summarize, it is vital to emphasize once again the importance of the clamping circuit. Even though it can introduce some error, careful component selection allows to find the balance between the performance and protection properties. It is important to use Schottky diodes, as only low voltage drop devices are able to bypass the internal ESD protection diodes placed at inputs of the op-amp, what ultimately prevents from unintended damage of the protected device.

Taking into account all information included in this paragraph, a proper clamping diode has been chosen. Its parameters are presented in the Table 3.5.

3.3.1.2 Buffering

This project is all about high impedance signals, what automatically forces designer to make the analog front-end "invisible" for the signal source. In order to do so, the input stage of the data acquisition board is supposed to draw as little current as possible.

The design requirements states the maximum peak-to-peak input voltage as high as 12V. This fact obliges to supply operational amplifiers using at least industry's standard $\pm 15V$ rails,

Table 3.5: Parameters of the selected parameter - taken from the datasheet [14]

Parameter	Value
Model	BAS40-02V-V-G
Manufacturer	Vishay Semiconductors
Type	Schottky
Package	SOD-523
Repetitive peak reverse voltage V_{RRM}	40V
Forward continuous current I_F	120mA
Leakage current I_R	20nA (Typ.)
Forward voltage V_F	380mV ($I_F=1mA$)

providing that op-amps used in the project would not get saturated. Rail-to-rail devices may be helpful in this situation.

Figure 3.6 presents the exact configuration of the op-amp circuit. It is called a voltage follower or a buffer. At this point, it is very important to once again look at the estimated current consumption of the input stage. Previous paragraph stated all unwanted current paths that deteriorate the performance of the entire circuit. The leakage current I_{leak} of diodes should be kept as low as possible (in order of nanoamperes). The another error source highlighted before is the input bias current I_{bias} of the operational amplifier's non-inverting input. Since the buffer circuit is used, the input impedance of the amplifier is limited by the I_{bias} only. Modern op-amps can draw as little bias current as a few picoamperes, therefore, the impact of this device is negligible providing that the proper integrated circuit will be used.

When designing op-amp circuits, it is important to match the impedance of both inputs in order to avoid output voltage offsets. In case when these impedances are not equal, offset voltages generated by the bias current of both inputs have no chance to cancel out, introducing another error source [13]. The compensating capacitor C_{comp} used in the feedback network (along with the feedback resistor R_{fb}) is forming an RC filter slowing down the amplifier's response and making it more stable, but it is necessary to keep its resonant frequency at reasonable level in order not to disturb the input signal.

After a market research, the appropriate operational amplifier has been found - see Table 3.6. At this point is possible to calculate the error voltage introduced by the input protection circuitry using Formula 3.1. Please note that it is the worst case scenario, when both diodes exhibit maximum leakage current.

$$\begin{aligned}
 V_{error} &= (R_{ser} \cdot (I_{bias} + I_{leak1} + I_{leak2})) \cdot A_u \\
 &= (1k\Omega \cdot (250pA + 20nA + 20nA)) \cdot 1 \\
 &= 40.25\mu V
 \end{aligned}$$

Of course, it is just a simple calculation that excludes such factors as temperature impact, tolerance of the resistor and so on. Having said that, the above-mentioned value is presented just to indicate the order of expected error.

3.3.1.3 Signal conditioning

A first step in capturing the incoming signal was buffering. Now, the signal has to be conditioned in order to allow full range measurement. As it can be imagined, the input range of popular microcontroller's ADCs is usually up to 5V and more often up to 3.3V. This fact introduces a need of some attenuation and biasing, since an AC signal is considered.

Table 3.6: Parameters of OPA4180 taken from the manufacturer's datasheet [14]

Parameter	Value
Model	OPA4180
Manufacturer	Texas Instruments
Supply voltage	$\pm 2\text{V}$ to $\pm 18\text{V}$
Bias current	250pA (typical)
Input offset voltage	75 μV (maximum)
Drift voltage	0.1 $\mu\text{V}/^\circ\text{C}$
Input voltage noise	0.25 μV_{pp}
Slew rate	0.8V/ μs

Attenuation is going to be performed by means of a voltage divider. Unfortunately, there are a few problems that may appear in this solution. The first one is the excessive loading of the circuit. High current is going to generate losses in a form of heat. Any resistor has a parameter called temperature coefficient, which describes the resistance change in a function of temperature (usually in ppm/ $^\circ\text{C}$) [15]. High temperature coefficient components are undesired in precision electronics, thus designers should avoid them by all means. Temperature-related problems could be solved in a couple of different ways. In case of this design, the voltage divider would consist of low temperature coefficient resistors buffered with an operational amplifier. This solution would allow for a negligible current draw. The Op Amp used for this purpose is exactly the same as in case of the input buffer - see Table 3.6.

At this point, it is time to introduce the signal biasing. This process is absolutely necessary, since the microcontroller is unable to capture negative voltage. This stage takes into account such aspects as input voltage range of the ADCs as well as the reference voltage value, as its value determines the maximum signal level distinguishable by the microprocessor.

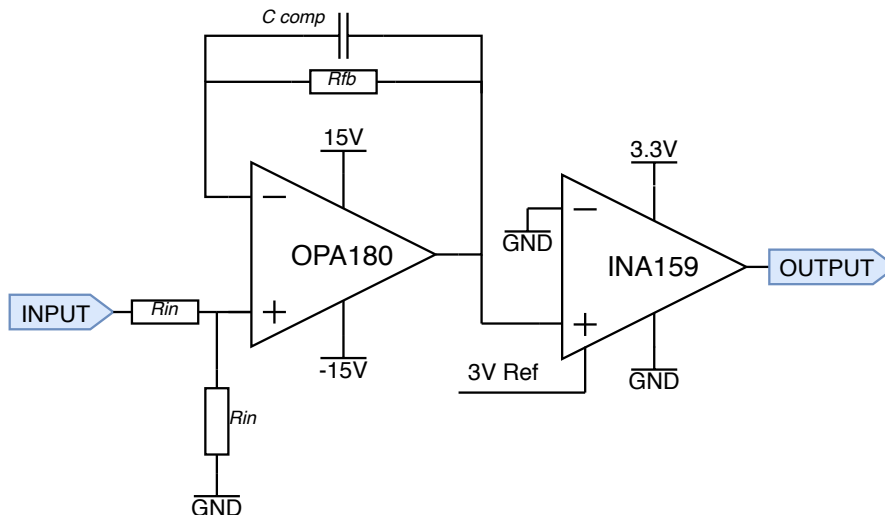


Figure 3.7: A circuit responsible for attenuation and level shifting

3.3.2 Voltage reference

The reference voltage source is an important building block in precision analog electronics. Due to the fact that the designed board utilizes the analog-to-digital converter with resolution

of at least 14-bits, it is important to follow particular design rules in order not to spoil its performance.

There are many different flavours of voltage reference sources, but the basic division includes zener and band-gap reference types [13]. Zener-based voltage incorporates a low-tempco zener diode and additional circuitry such as a matching silicon diode cancelling the influence of the temperature coefficient. Quite often, such references include internal heaters in order to maintain relatively stable temperature of the diode, therefore reducing the temperature impact. It is worth to highlight that such references may get quite expensive and very often offer only high reference voltage values, thus some additional circuitry may be required for interfacing the a microcontroller [13].

The second type of voltage reference sources is called the band-gap reference voltage. This type is based on matched transistors, and with some additional circuitry, it is able to provide lower (and precisely trimmed) reference voltages with comparable temperature coefficients. Moreover, such references may include internal buffer, thus no additional circuitry is often required [13].

The most important parameters of the voltage reference source are the mentioned temperature coefficient and output voltage tolerances. Due to the fact that band-gap references are readily available and offer suitable reference voltage levels, this type of solution would be considered in this design.

Table 3.7: Parameter of REF5030 taken from the manufacturer's datasheet [16]

Parameter	Value
Model	REF5030
Manufacturer	Texas Instruments
Temperature drift (max)	8ppm/°C
Output voltage tolerance (max)	0.1%
Output current (max)	10mA
Type	Band-gap
Reference voltage value	3.0V

3.3.3 Microprocessor selection

The microcontroller is a brain of the data acquisition board. As it can be imagined, it is responsible for such tasks as analog-to-digital conversion, data processing and communication with a personal computer. In addition, it is going to provide a basic user interface by means of buttons and switches for configuration purposes and signalling LEDs. Apart from that, there should be some space for calibration process, as well as triggering signals, thus additional I/Os would be included on the board for user-friendliness.

The Table 3.2 listed some of design requirements applicable for the MCU, namely, the ADC resolution as well as minimum sampling rate. In addition to that, the microprocessor has to be equipped with sufficient amount of inputs and outputs as well as communication interfaces in order to provide reliable connectivity with the PC.

By following mentioned requirements, the device presented in the Table 3.8 has been selected for this design. It is worth to highlight its superior analog features, namely the analog-to-digital converter capable of producing 16-bit results when the appropriate layout and averaging of recorded samples are implemented (the device incorporates a native 14-bit SAR core) [18]. Apart from analog-related features, the selected MSP432 provides numerous digital interfaces,

Table 3.8: Features of MSP432P401R taken from the manufacturer's datasheet [17]

Parameter	Value
Model	MSP432P401R
Manufacturer	Texas Instruments
Architecture	32-bit ARM
Clock frequency	48MHz
Flash memory	256KB
SRAM memory	64KB
ADC resolution	up to 16-bit
ADC sampling rate	up to 1Msps
ADC input channels	up to 24
UART channels	4
UART max. baud rate	460800bps
SPI channels	4
SPI max. baud rate	16Mbps

what comes in handy when a connection with a personal computer is required. In this design, the primary communication channel would be based on UART, but is also planned to include an SPI-to-USB bridge for experimental purposes.

3.3.3.1 Architecture

Once the right microcontroller has been selected, one has to think about its peripherals required to allow easy connectivity as well as user-friendly interface. A general architecture of the designed system is presented in the Figure 3.8. In the following sections, all major sections would be briefly introduced.

3.3.3.2 ADC

The analog-to-digital converter is the most important part of the entire system. According to the manufacturer's description [17], the selected device is able to achieve 16-bit precision with software over-sampling. The sampling rate is resolution dependent and for 14-bit mode, MSP432 is able to provide 1Msps. It is vital to point out that for better precision, the external voltage reference source is used.

3.3.3.3 External voltage reference

As mentioned in the previous paragraph, the MCU is equipped with the external reference voltage source in order to improve stability of the ADC. The selected device (REF5030) provides such features as the accuracy as low as 0.1% and temperature drift lower than 8ppm/°C [16]. The built-in reference has only 1% accuracy and temperature drift up to 60ppm/°C [17]. MSP432 devices provide dedicated voltage reference input terminals (+VREF and -VREF) to facilitate the described modification.

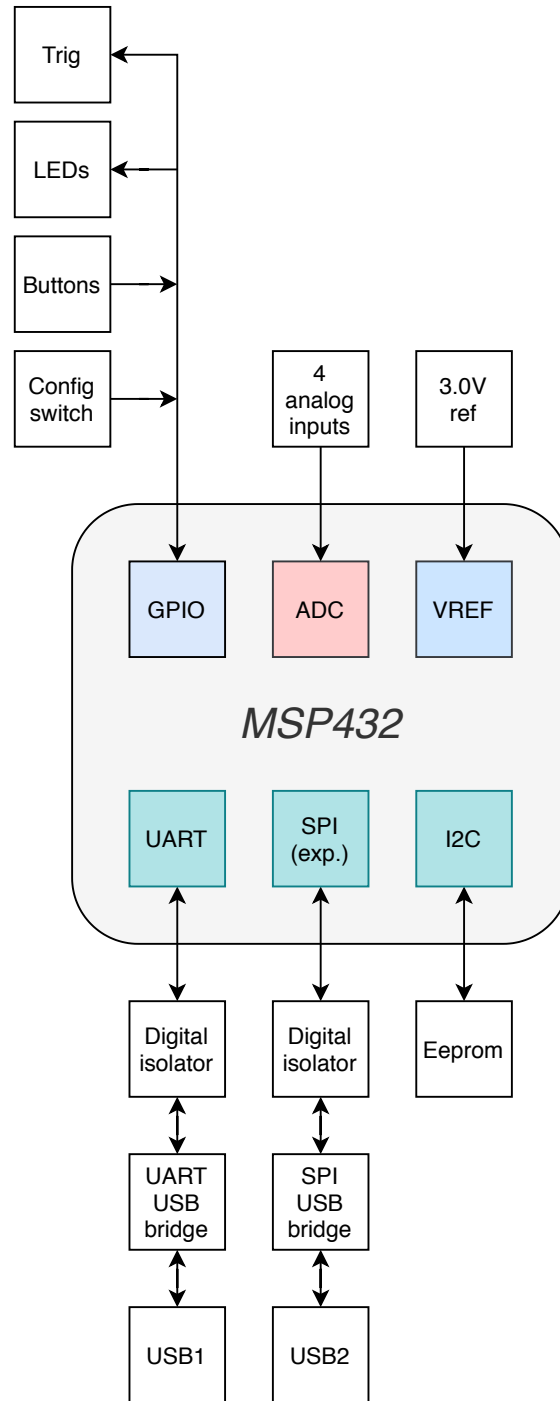


Figure 3.8: Architecture of the microcontroller and its peripherals

3.3.3.4 User interface

The purpose of the data acquisition board is to allow easy and precise measurement of high impedance signals with a focus on piezoelectric-based circuits. The standard way of communication between the board and user is maintained by means of a personal computer, but there is some space for improvement.

It is planned to incorporate some basic functionalities based on switches and buttons. A 4-channel DIP switch is designated for configuration purposes. There are also two momentary buttons allowing to control the measurement process. An RGB LED is used for status

indication.

In addition, there is a dedicated trigger pin that could be used to synchronize the board with a signal or with an external measurement instrument.

3.3.3.5 Connectivity

The designed device utilizes a few digital interfaces to communicate with peripherals and the personal computer. UART and SPI are used for data streaming and for parsing commands. I2C interface is used for communication with an EEPROM memory storing calibration constants and some basic info related to the device. At this point it is important to point out that SPI interface is for experimental purposes only, therefore UART is assumed to be the basic interface between the computer and the board.

Since the data acquisition module is galvanically isolated from the computer, all signals has to include additional isolating devices. In case of the UART, Rx and Tx signals are separated between primary and secondary side of the board by means of an Analog Devices ADuM1201 digital isolator. According to the manufacturer's datasheet [19], it supports data rates up to 25Mbps and 2500V RMS isolation for 1 minute per UL 1577. SPI interface is isolated using Maxim Integrated MAX14851 six-channel digital isolator. It is supporting data rates as high as 50Mbps and isolation of 600V RMS for 1 minute [20].

In order to make the device compatible with USB protocol, it is necessary to provide signal bridges for UART and SPI interfaces. This way, the user would be able to easily connect the data acquisition board directly to the personal computer. The USB-to-UART bridge parameters are stated in the Table 3.9. It supports baud rates up to 1Mbps, which makes it suitable for this design. It is important to point out that CP2012 is fully compatible with most popular operating systems.

Table 3.9: Features of CP2102 taken from the manufacturer's datasheet [21]

Parameter	Value
Model	CP2102
Manufacturer	Silicon Labs
Max. baud rate	1Mbps
On-chip voltage regulator	3.3V
USB 2.0 compliant	Yes
Transmit buffer	640 bytes
Receive buffer	576 bytes
USB powered	Yes
Compatibility	Windows/Linux/Mac

The USB-to-SPI bridge is also manufactured by *Silicon Labs* - see Table 3.10. The most important features of this device are the maximum baud rate of 12MHz and 11 fully configurable GPIOs. Due to the fact that SPI is just an experimental mean of communication in this project, there would be no more focus on SPI-related circuitry.

REFERENCES

Table 3.10: Parameters of CP2130 taken from the manufacturer's datasheet [22]

Parameter	Value
Model	CP2130
Manufacturer	Silicon Labs
Max. SPI clock	12MHz
On-chip voltage regulator	3.45V
USB 2.0 compliant	Yes
Operation modes	3 or 4-wire
Configurable GPIOs	11
USB powered	Yes
Compatibility	Windows

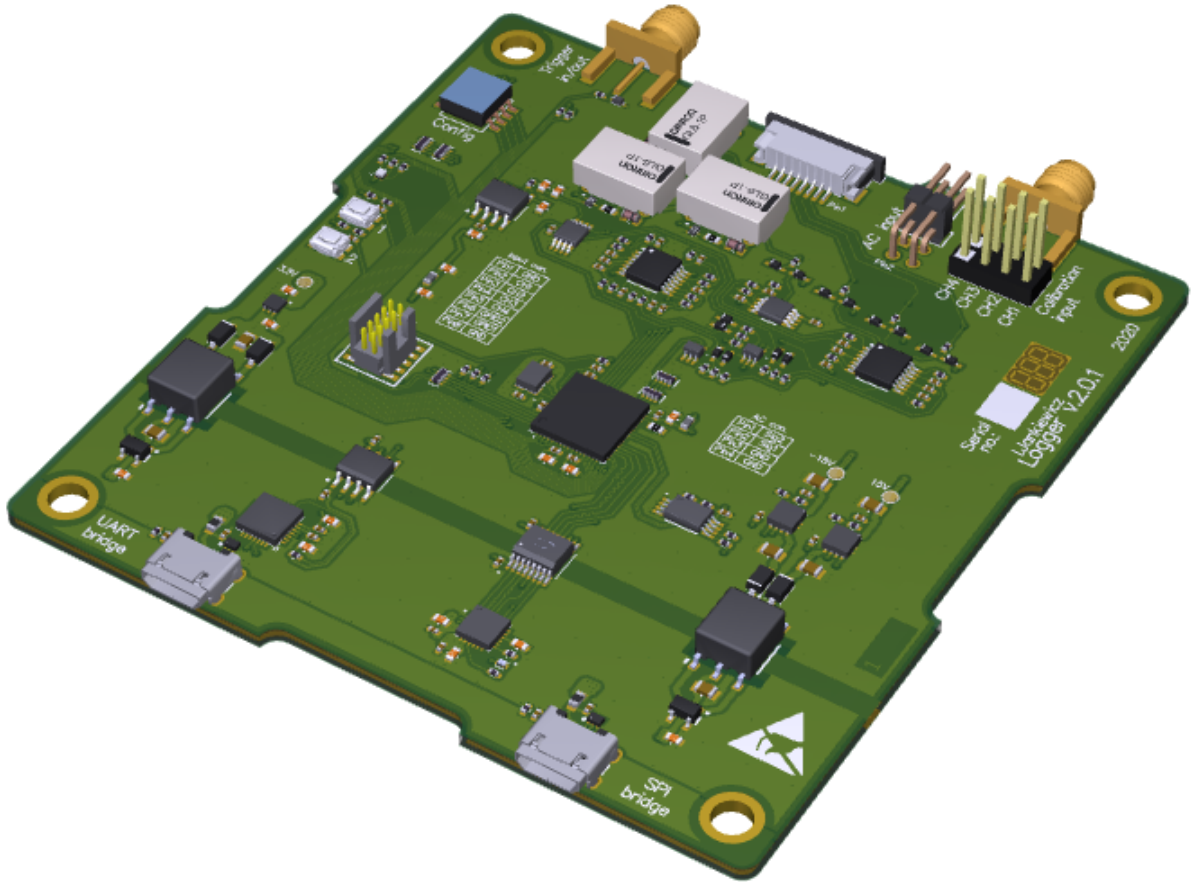


Figure 3.9: Data acquisition board 3D model

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